



#### We2G-1

# A Compact 140-GHz Radar MMIC with I-Q Downconverter in SiGe BiCMOS Technology

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## **Presentation Outline**



- Monostatic Doppler Radar
- I/Q Diode Mixer
- Circuit Realization
- Measurement and Results
- Concept Comparison
- Summary and Outlook





## **Monostatic Doppler Radar**



#### Continuous wave radar:

Permanent transmission of RF signal with constant frequency

#### Conventional monostatic radar:

- One antenna for both transmitted and received signal
- Typically requires coupler to seperate RX/TX paths

## I/Q Mixer realization:

- Allows to obtain phase information
- Typically realized by 90-deg coupler







## **Monostatic Doppler Radar**



## **D-band Doppler Radar:**

- D-band frequencies (110 to 170 GHz) increasingly relevant for radar systems
- Doppler radar:  $f_D = \frac{2v_r}{\lambda} \sim f_{TX}$  with  $\lambda = \frac{c}{f_{TX}}$
- Compact Doppler sensor realization:
  - monostatic structure (single RX/TX antenna)
  - low current consumption (passive mixer)





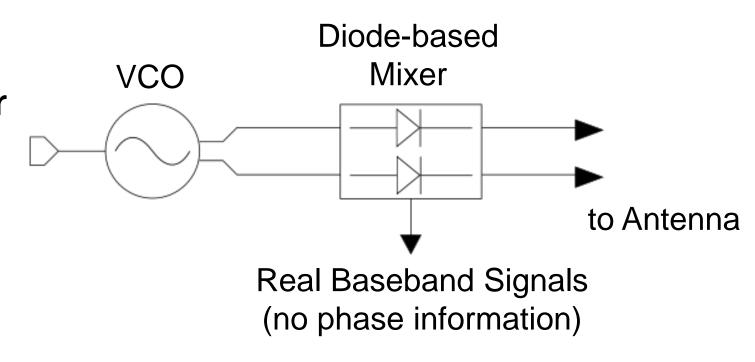
## **Monostatic Doppler Radar**



## Conventional Diode Mixer Topology

- No dedicated ratrace coupler for monostatic radar system
  - Enables better SNR
  - Enables compact layout realization

 No phase information, redundant baseband signals





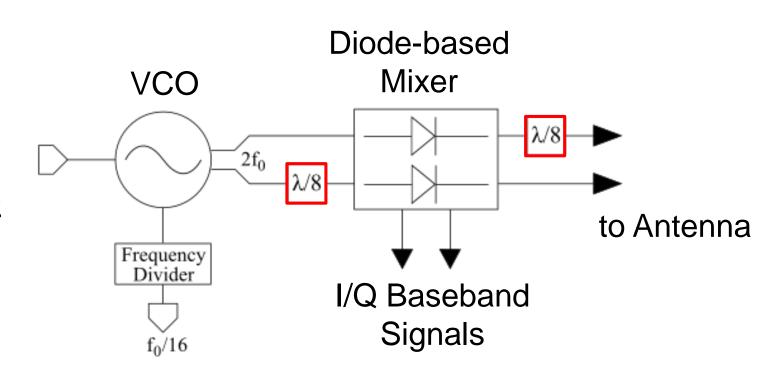


## I/Q Diode Mixer



## Adaptions for I/Q output:

- Shifted λ/8 lines added
  - result in relative 90° shift for baseband signals
  - I/Q signal at baseband output provides additional phase information
- Differential output signal to antenna not affected



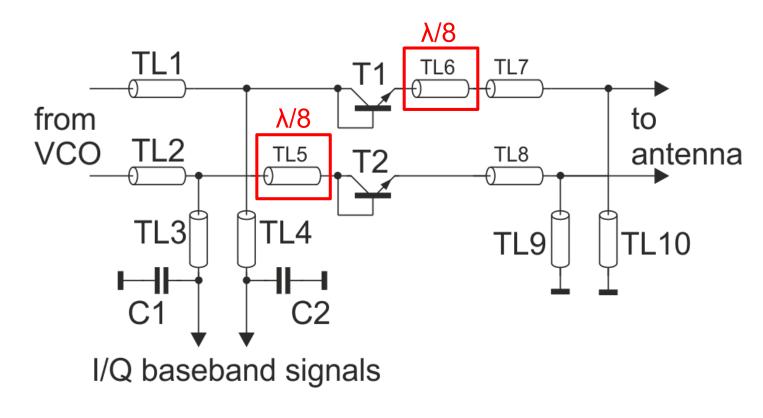




## I/Q Diode Mixer



- Transistors T1, T2 as mixing diodes
  - small bias current through diodes
- λ/4 lines TL3, TL4 transform
   RF short (C1, C2) into open
- Stub lines TL9, TL10
  - compensate parasitic pad capacitance
  - provide return path for mixer bias current diodes







## I/Q Diode Mixer



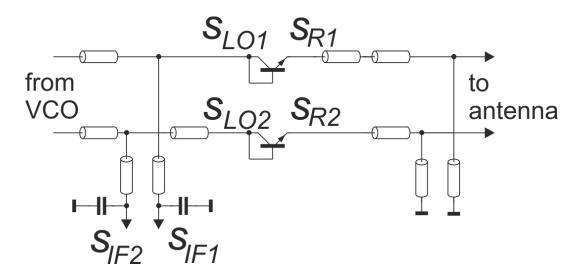
• 
$$s_{LO1}(t) = cos(2\pi f_0 t + \varphi_0)$$

• 
$$s_{LO2}(t) = cos\left(2\pi f_0 t + \varphi_0 - \pi - \frac{\pi}{4}\right)$$

• 
$$s_{R1}(t) = cos\left(2\pi(f_0 \pm f_D)t + \varphi_{RX} - \frac{\pi}{4}\right)$$

• 
$$s_{R2}(t) = cos(2\pi(f_0 \pm f_D)t + \varphi_{RX} - \pi)$$

- Phase shift due to differential signal
- Phase shift due to shifted  $\lambda/8$  lines



**Baseband output:** 

$$\Delta \varphi = \pm \frac{\pi}{2}$$

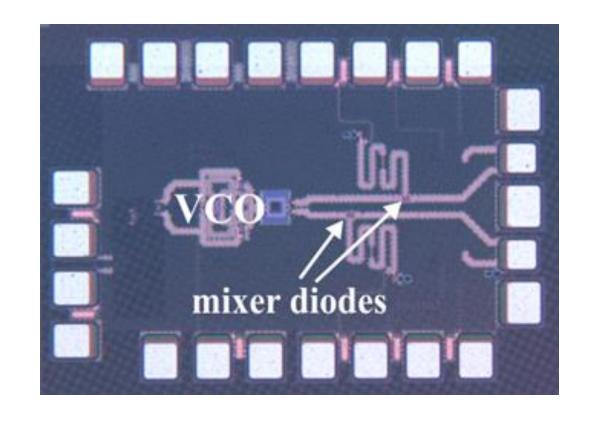




## **Circuit Realization**



- Circuit realized with on-chip Dband VCO
- Infineon's 130nm SiGe BiCMOS process B11HFC
- fT/fmax = 250 GHz/370 GHz
- 800×1160µm² (including pads)





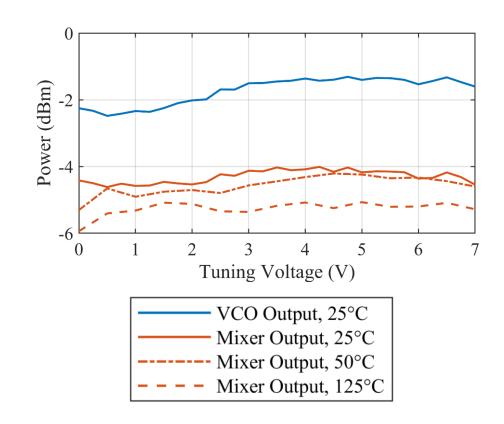


## Measurement and Results



## **Transmitted Power over Temperature**

- Diode insertion loss ≈ 2,5 dB
- Moderate decrease of output power at 125°C
- Transceiver remains functional at temperatures > 200°C (sufficient output power for meaningful Doppler measurements)





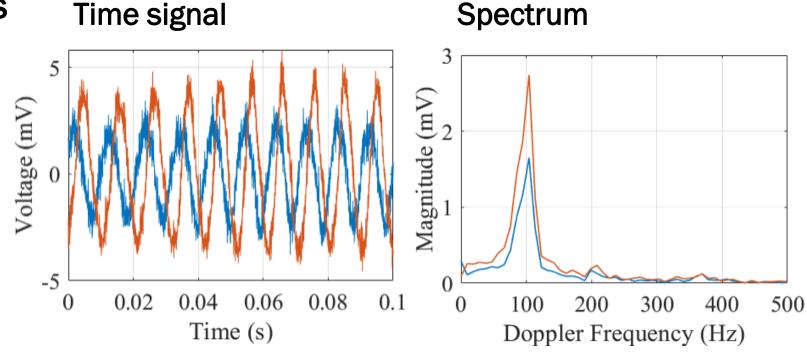


## Measurement and Results



## Moving Target with Constant Radial Velocity

- Radial velocity 0.11 m/s
- Transient voltage signals with consistent phase shift (no change in direction)
- Doppler spectrum shows corresponding peak at 102 Hz





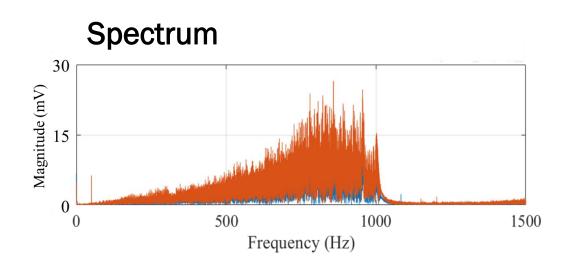


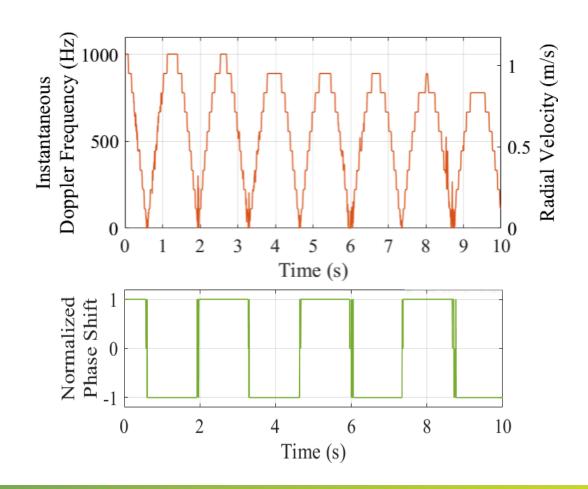
## Measurement and Results



## Moving Target with Periodically Oscillating Radial Velocity

Corner Reflector mounted on pendulum, oscillating in radial direction to antenna









## **Concept Comparison**



	[9]	[10]	[5]	This Work
Frequency	160 GHz*	122 GHz*	144.6-	136-146 GHz
Range			160 GHz	
RF Channels	2x1 RX/TX	2 RX, 1 TX	1 RX/TX	1 RX/TX
	(monostatic, with		(monostatic)	(monostatic)
	rat race coupler)			
RX Mixer	Gilbert-cell	Gilbert-cell	diode-based	diode-based (IQ
	(IQ output)	(IQ output)		output)
IQ Realization	90-degree coupler	90-degree coupler	n/a	shifted diodes/
	(branchline)			t-lines
TX Signal	external LO with on-	external LO with on-	on-chip	on-chip
Generation	chip PA	chip PA	power VCO	power VCO

<sup>\*</sup> center frequency (external LO input)







## **Summary and Outlook**



## **Summary:**

- Compact monostatic D-band Doppler transceiver
- No 90-deg coupler needed for I/Q, no Ratrace coupler needed for RX/TX separation
- System still working at temperatures > 150°C

#### **Outlook:**

- On-chip VCO allows FMCW radar operation
- Adjustable diode current possibly allows tradeoff of NF and P<sub>out</sub>

